

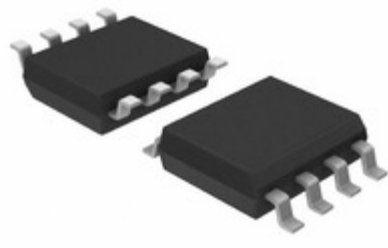







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|  <p>TOSHIBA Leading Innovation >>></p> | <p>GT10G131(TE12L,Q)</p> |
| | <p>Hersteller-Teilenummer: GT10G131(TE12L,Q)</p> <p>Hersteller / Marke: Toshiba Semiconductor and Storage</p> <p>Teil der Beschreibung: IGBT 400V 1W 8-SOIC</p> <p>Datenblätter:  GT10G131(TE12L,Q).pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
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| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

| | |
|-----------------------------------------------|---------------------------------------------------------|
| Teilenummer | GT10G131(TE12L,Q) |
| Hersteller | Toshiba Semiconductor and Storage |
| Beschreibung | IGBT 400V 1W 8-SOIC |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-IGBTs-Einzel |
| Teilstatus | Require For Quote & Check Stock |
| Spannung - Kollektor-Emitter-Durchbruch (max) | 400V |
| VCE (on) (Max) @ Vge, Ic | 2.3V @ 4V, 200A |
| Testbedingung | - |
| Td (ein / aus) bei 25 ° C | 3.1µs/2µs |
| Schaltenergie | - |
| Supplier Device-Gehäuse | 8-SOP (5.5x6.0) |
| Serie | - |
| Leistung - max | 1W |
| Verpackung | Tape & Reel (TR) |
| Verpackung / Gehäuse | 8-SOIC (0.173", 4.40mm Width) |
| Betriebstemperatur | 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Eingabetyp | Standard |
| IGBT-Typ | - |
| Strom - Collector Pulsed (Icm) | 200A |
| Strom - Kollektor (Ic) (max) | - |

GT10G131(TE12L,Q) Electronic Components ist ein 100% neues Original von YIC Distributor, GT10G131(TE12L,Q)-Datenblätter durchsuchen, PDF, Inventar bei Y-IC.com Online, GT10G131(TE12L,Q) Toshiba Semiconductor and Storage mit Garantie und Vertrauen bestellen. Versand per DHL / FedEx / TNT / UPS Express. Unterstützung der Zahlung mit telegrafischer Überweisung (T / T) oder PayPal.
RFQ GT10G131(TE12L,Q) E-Mail: Info@Y-IC.com

Sie können auch interessiert

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| <p>sein:</p>  <p>GT10J303 TOS GT10J303 TOS</p> |  <p>GT10G102 TOSHIBA GT10G102 TOSHIBA</p> |  <p>GT10G101 TOSHIBA GT10G101 TOSHIBA</p> |  <p>GT10J312 TOSHIBA GT10J312 TOSHIBA</p> |
|  <p>GT10J101 TOS GT10J101 TOS</p> |  <p>GT10B-(20PRE)/RE-MD Hirose TOOL EXTRACTION</p> |  <p>GT10B-(20SET)/RE-MD Hirose TOOL EXTRACTION</p> |  <p>GT10B-(CON)/RE-MD Hirose TOOL EXTRACTION</p> |

Verwandtes Hot-Keyword

Mehr

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|-----------------------------------------------------|-------------------------------|--------------------------------|-------------------------|------------------------------------|
| GT10G131(TE12L,Q) Toshiba Semiconductor and Storage | GT10G131(TE12L,Q) Datenblatt | GT10G131(TE12L,Q)-Datenblätter | GT10G131(TE12L,Q) PDF | Toshiba Semiconductor and Storage |
| GT10G131(TE12L,Q) Electronic | GT10G131(TE12L,Q)-Komponenten | GT10G131(TE12L,Q)-Verteiler | GT10G131(TE12L,Q)-Bild | GT10G131(TE12L,Q)-Teil |
| GT10G131(TE12L,Q) Preis | GT10G131(TE12L,Q) Hersteller | GT10G131(TE12L,Q) Bild | GT10G131(TE12L,Q) Aktie | GT10G131(TE12L,Q) Inventar |
| GT10G131(TE12L,Q) Neu | GT10G131(TE12L,Q) Original | GT10G131(TE12L,Q) garantiert | GT10G131(TE12L,Q) RFQ | GT10G131(TE12L,Q) Online bestellen |